

GaAs MMIC SUB-HARMONICALLY PUMPED MIXER, 26 - 33 GHz

Typical Applications

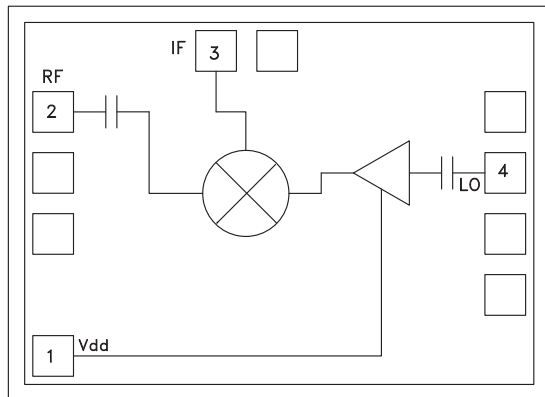
The HMC338 is ideal for:

- General Purpose Applications
- 26 and 33 GHz Microwave Radios
- Up and Down Converter for Point-to-Point Radios
- Satellite Communication Systems

Features

- Integrated LO Amplifier: -5 dBm Input
- Sub-Harmonically Pumped (x2) LO
- High 2LO/RF Isolation: 33 dB
- Die Size: 1.32 x 0.97 x 0.1 mm

Functional Diagram



General Description

The HMC338 chip is a general purpose sub-harmonically pumped (x2) MMIC mixer with an integrated LO amplifier which can be used as an upconverter or downconverter in the 26 to 33 GHz frequency range. The chip utilizes a GaAs PHEMT technology that results in a small overall chip area of 1.28mm². The 2LO to RF isolation is excellent eliminating the need for additional filtering. The LO amplifier is a single bias (+3V to +4V) two stage design with only -5 dBm nominal drive requirement. All data is measured with the chip in a 50 ohm test fixture connected via 0.076 mm (3 mil) ribbon bonds of minimal length <0.31 mm (<12 mils).

Electrical Specifications, $T_A = +25^\circ\text{C}$, As a Function of Vdd

Parameter	IF = 1 GHz LO = -5 dBm & Vdd = +4V			IF = 1 GHz LO = -5 dBm & Vdd = +3V			Units
	Min.	Typ.	Max.	Min.	Typ.	Max.	
Frequency Range, RF	26 - 33			27 - 32			GHz
Frequency Range, LO	13 - 16.5			13.5 - 16			GHz
Frequency Range, IF	DC - 2.5			DC - 2.5			GHz
Conversion Loss		9	12		9	12	dB
Noise Figure (SSB)		9	12		9	12	dB
2LO to RF Isolation	18	33		12	30		dB
2LO to IF Isolation	30	40		25	40		dB
IP3 (Input)	5	11		3	9		dBm
1 dB Compression (Input)	-5	2		-5	0		dBm
Supply Current (I _{dd})		28	50		25	50	mA

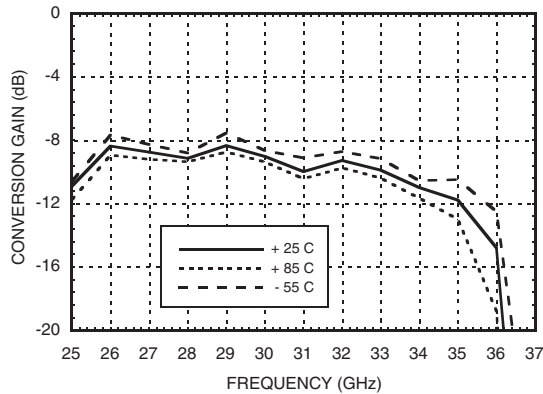
*Unless otherwise noted, all measurements performed as downconverter, IF= 1 GHz.

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

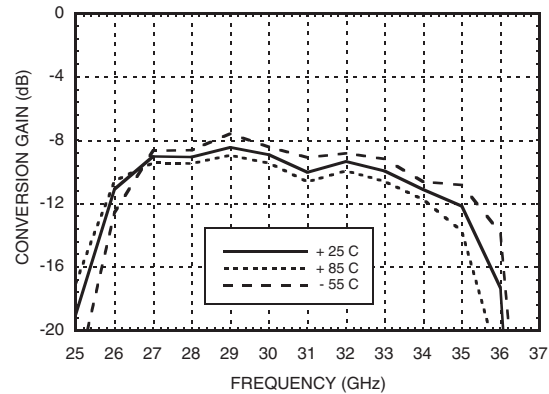
For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D

GaAs MMIC SUB-HARMONICALLY PUMPED MIXER, 26 - 33 GHz

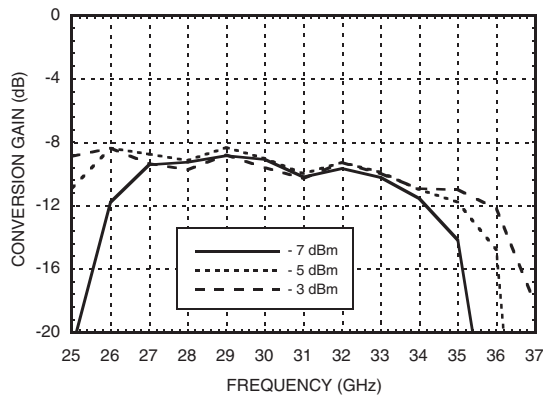
Conversion Gain vs. Temperature @ LO = -5 dBm, Vdd = +4V



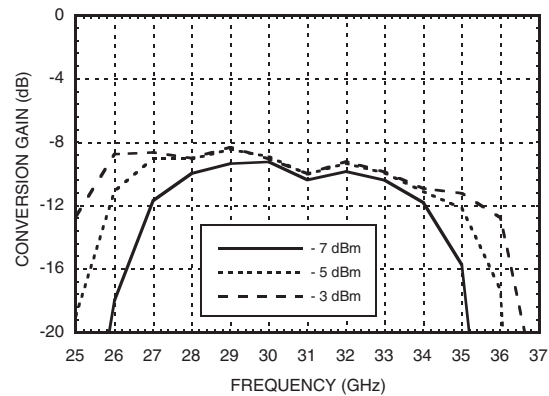
Conversion Gain vs. Temperature @ LO = -5 dBm, Vdd = +3V



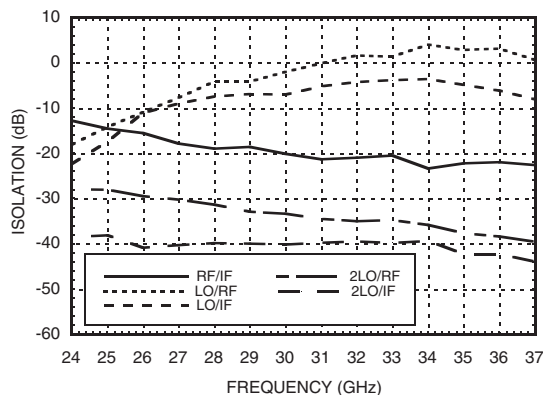
Conversion Gain vs. LO Drive @ Vdd = +4V



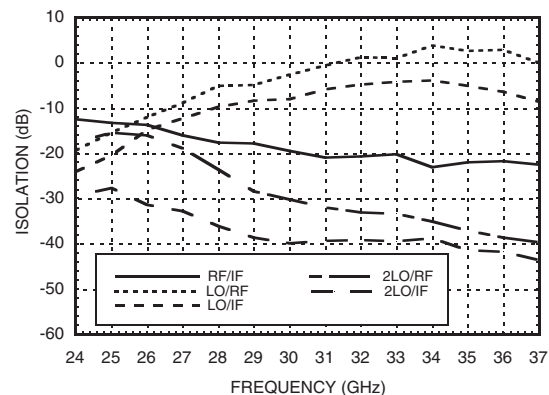
Conversion Gain vs. LO Drive @ Vdd = +3V



Isolation @ LO = -5 dBm, Vdd = +4V



Isolation @ LO = -5 dBm, Vdd = +3V

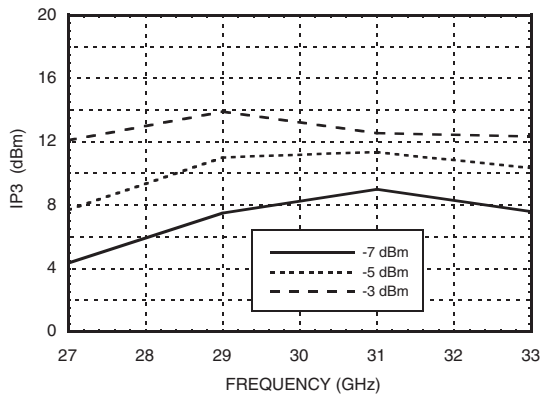


Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

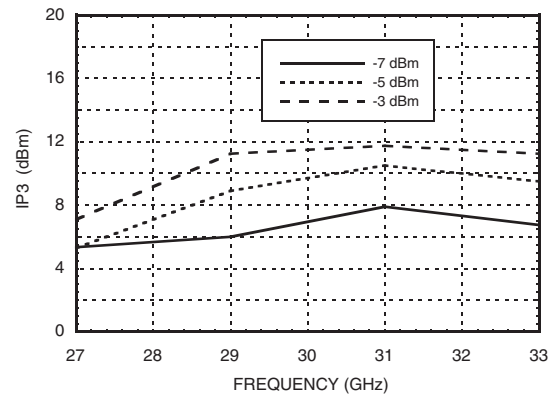
For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D

GaAs MMIC SUB-HARMONICALLY PUMPED MIXER, 26 - 33 GHz

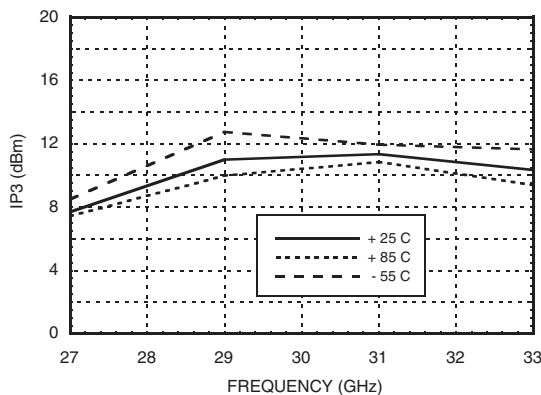
Input IP3 vs. LO Drive @ Vdd = +4V*



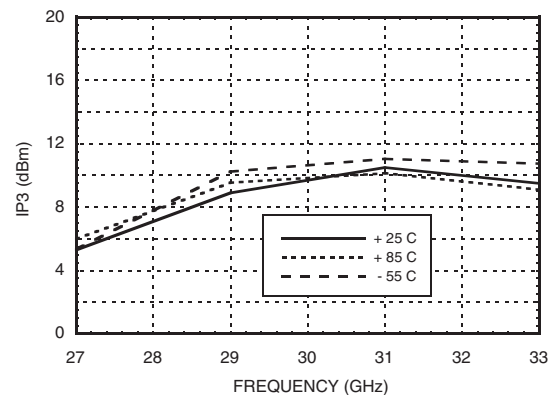
Input IP3 vs. LO Drive @ Vdd = +3V*



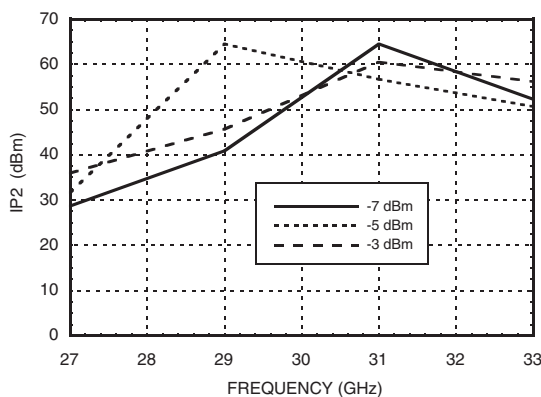
Input IP3 vs. Temperature @ LO = -5 dBm, Vdd = +4V*



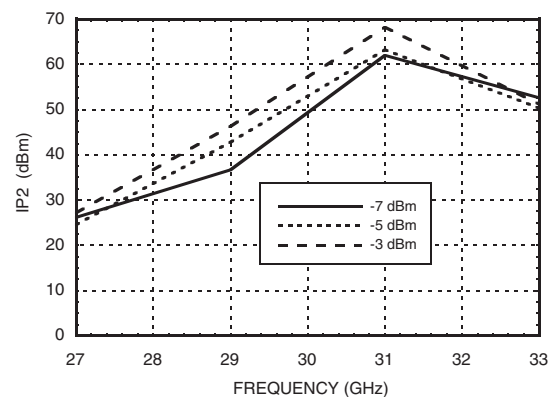
Input IP3 vs. Temperature @ LO = -5 dBm, Vdd = +3V*



Input IP2 vs. LO Drive @ Vdd = +4V*



Input IP2 vs. LO Drive @ Vdd = +3V*



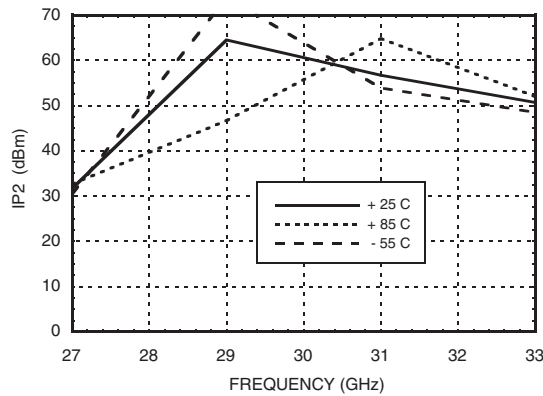
* Two-tone input power = -10 dBm each tone, 1 MHz spacing.

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

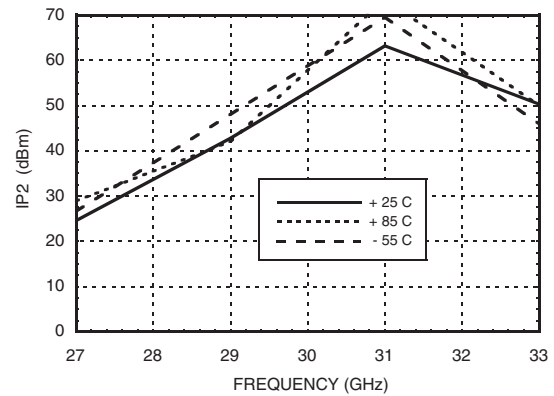
For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D

GaAs MMIC SUB-HARMONICALLY PUMPED MIXER, 26 - 33 GHz

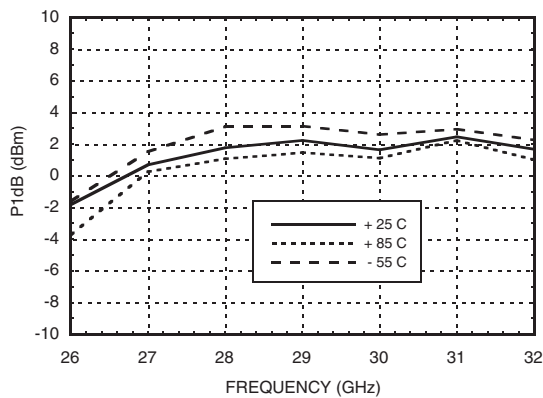
Input IP2 vs. Temperature
@ LO = -5 dBm, Vdd = +4V*



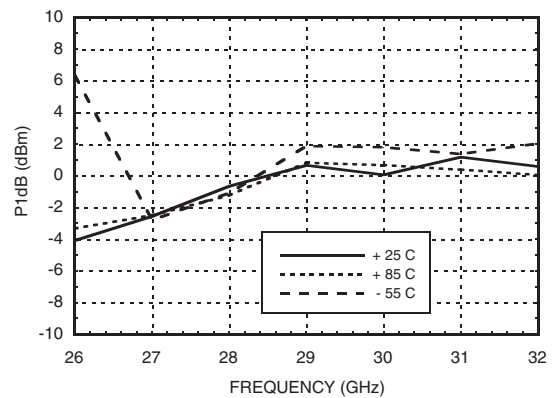
Input IP2 vs. Temperature
@ LO = -5 dBm, Vdd = +3V*



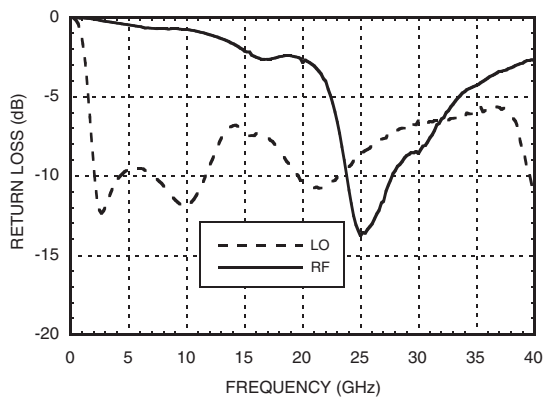
Input P1dB vs. Temperature
@ LO = -5 dBm, Vdd = +4V



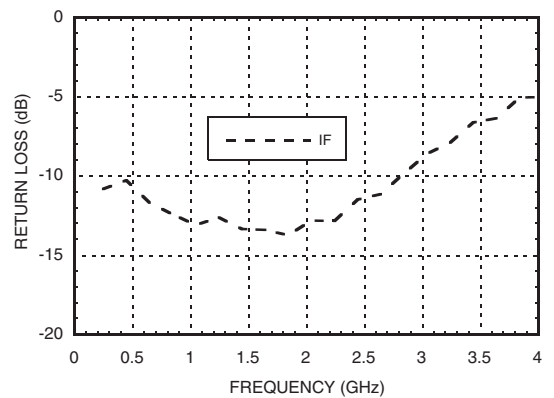
Input P1dB vs. Temperature
@ LO = -5 dBm, Vdd = +3V



RF & LO Return Loss
@ LO = -5 dBm, Vdd = +4V



IF Return Loss
@ LO = -5 dBm, Vdd = +4V



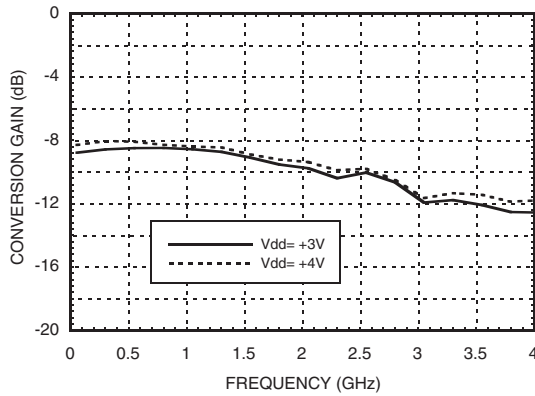
* Two-tone input power = -10 dBm each tone, 1 MHz spacing.

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

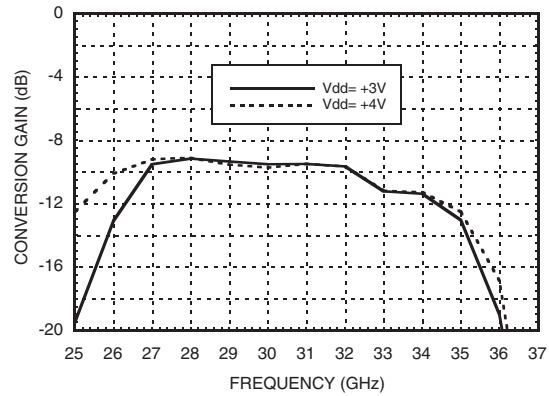
For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D

**GaAs MMIC SUB-HARMONICALLY
PUMPED MIXER, 26 - 33 GHz**

IF Bandwidth @ LO = -5 dBm



**Upconverter Performance
Conversion Gain, LO = -5 dBm, Vdd = +4V**



MxN Spurious @ IF Port, Vdd = +4V

mRF	nLO					
	±5	±4	±3	±2	±1	0
-3						
-2	52					
-1	54	35	53			
0			4	28	-8	
1				X	51	13
2		58	51		42	
3	88					

RF = 31 GHz @ -10 dBm
LO = 15 GHz @ -5 dBm
All values in dBc below IF power level.
Measured as downconverter

MxN Spurious @ RF Port, Vdd = +4V

mIF	nLO					
	±5	±4	±3	±2	±1	0
-3				49		
-2			33	55	45	
-1			41	X	43	
0			-5	19	-16	
1			44	X	40	15
2			33	54	36	63
3				47		69

IF = 1 GHz @ -10 dBm
LO = 15 GHz @ -5 dBm
All values in dBc below RF power level.
Measured as upconverter

GaAs MMIC SUB-HARMONICALLY PUMPED MIXER, 26 - 33 GHz

Absolute Maximum Ratings

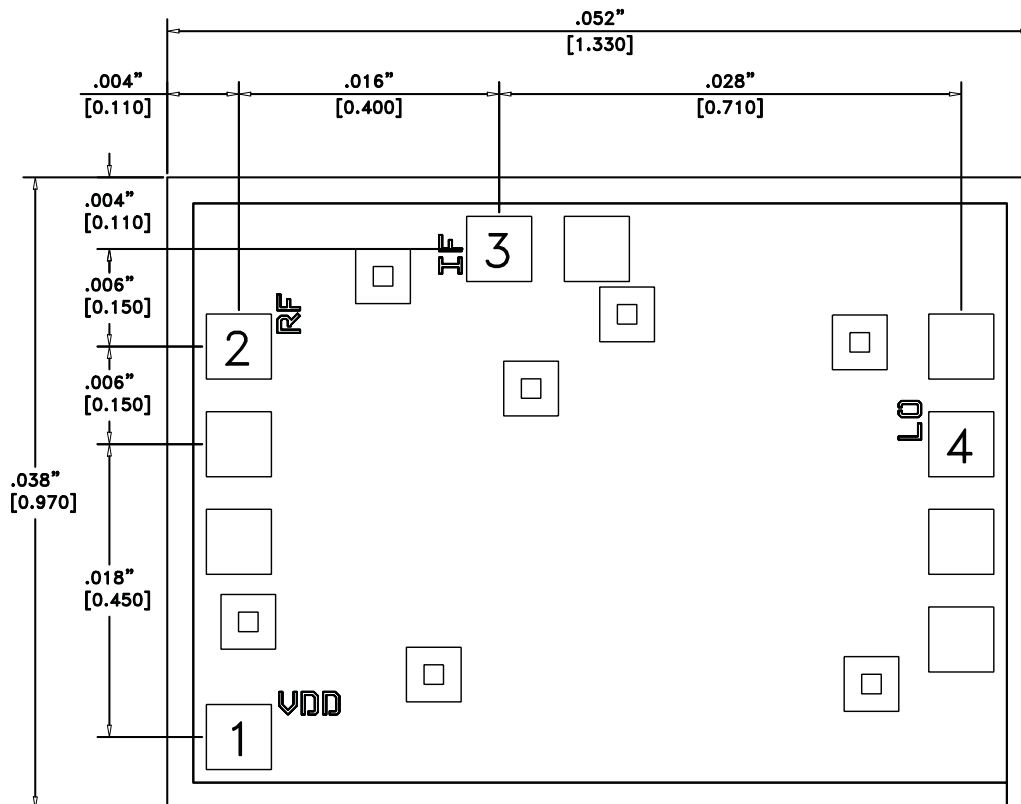
RF / IF Input (Vdd = +5V)	+13 dBm
LO Drive (Vdd = +5V)	+13 dBm
Vdd	+5.5 Vdc
Continuous P _{diss} (Ta = 85 °C) (derate 2.64 mW/°C above 85 °C)	238 mW
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

3

Outline Drawing



Die Packaging Information ^[1]

Standard	Alternate
GP-2 (Gel Pack)	[2]

[1] Refer to the "Packaging Information" section for die packaging dimensions.

[2] For alternate packaging information contact Hittite Microwave Corporation.

NOTES:

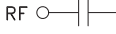
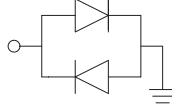
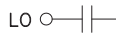
1. ALL DIMENSIONS IN INCHES (MILLIMETERS)
2. ALL TOLERANCES ARE ±0.001 (0.025)
3. DIE THICKNESS IS 0.004 (0.100) BACKSIDE IS GROUND
4. BOND PADS ARE 0.004 (0.100) SQUARE
5. BOND PAD SPACING, CTR-CTR: 0.006 (0.150)
6. BACKSIDE METALLIZATION: GOLD
7. BOND PAD METALLIZATION: GOLD

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

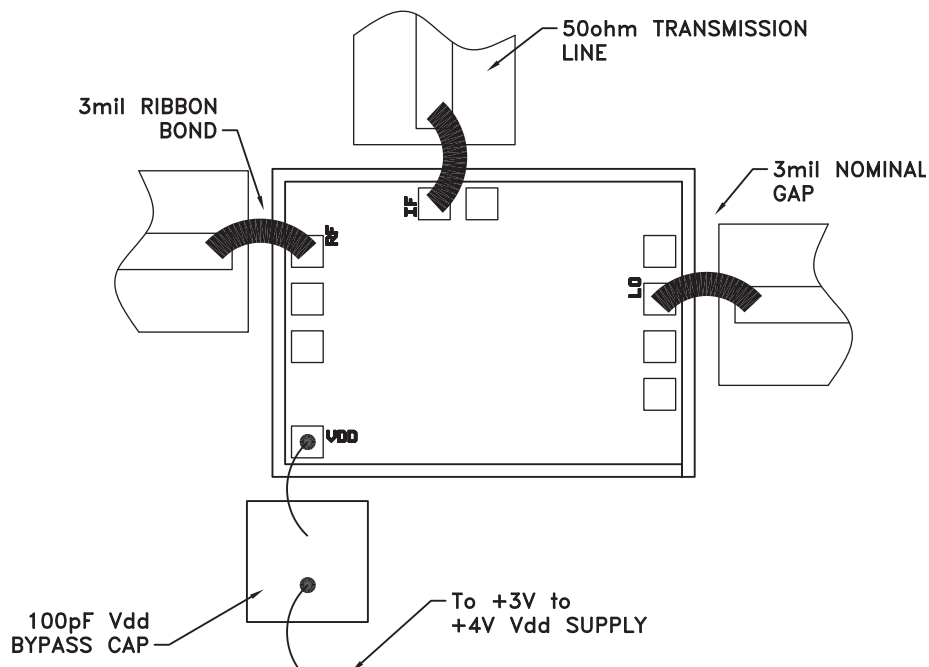
For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106
Phone: 781-329-4700 • Order online at www.analog.com
Application Support: Phone: 1-800-ANALOG-D

GaAs MMIC SUB-HARMONICALLY PUMPED MIXER, 26 - 33 GHz

Pad Descriptions

Pad Number	Function	Description	Interface Schematic
1	Vdd	Power supply for the LO Amplifier. An external RF bypass capacitor of 100 - 330 pF is required. A MIM border capacitor is recommended. The bond length to the capacitor should be as short as possible. The ground side of the capacitor should be connected to the housing ground.	
2	RF	This pad is AC coupled and matched to 50 Ohm.	RF 
3	IF	This pad is DC coupled and should be DC blocked externally using a series capacitor whose value has been chosen to pass the necessary IF frequency range. Any applied DC voltage to this pin will result in die non-function and possible die failure.	
4	LO	This pad is AC coupled and matched to 50 Ohm.	LO 

Assembly Diagram



Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D